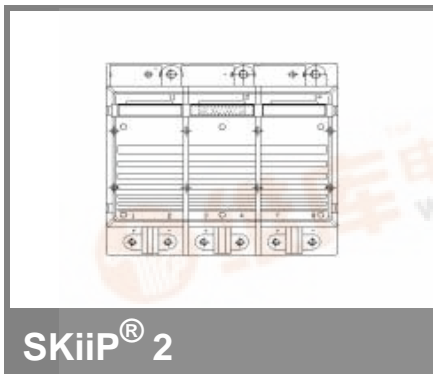


SKiIP 942GB120-3D



2-pack - integrated intelligent Power System

Power section

SKiIP 942GB120-3D

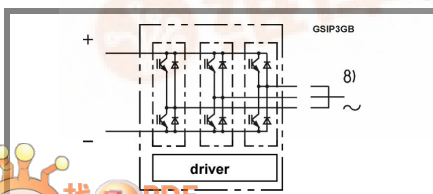
Features

- SKiIP technology inside
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiIP® 2 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized file no. E63532

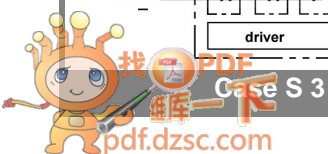
- 1) with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)
- 8) AC connection busbars must be connected by the user; copper busbars available on request

Absolute Maximum Ratings		$T_s = 25\text{ }^\circ\text{C}$ unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT			
V_{CES}	Operating DC link voltage	1200	V
$V_{CC}^{(1)}$		900	V
V_{GES}		± 20	V
I_C	$T_s = 25\text{ (70) }^\circ\text{C}$	900 (675)	A
Inverse diode			
$I_F = -I_C$	$T_s = 25\text{ (70) }^\circ\text{C}$	900 (675)	A
I_{FSM}	$T_j = 150\text{ }^\circ\text{C}$, $t_p = 10\text{ ms}$; sin.	6480	A
I^2t (Diode)	Diode, $T_j = 150\text{ }^\circ\text{C}$, 10 ms	210	kA ² s
T_j , (T_{stg})		- 40 (- 25) ... + 150 (125)	$^\circ\text{C}$
V_{isol}	AC, 1 min. (mainterminals to heat sink)	3000	V

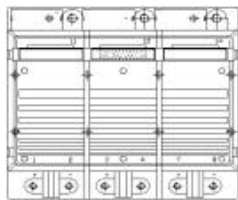
Characteristics		$T_s = 25\text{ }^\circ\text{C}$ unless otherwise specified							
Symbol	Conditions	min.	typ.	max.	Units				
IGBT									
V_{CEsat}	$I_C = 750\text{ A}$, $T_j = 25\text{ (125) }^\circ\text{C}$		2,6 (3,1)	3,1	V				
V_{CEO}	$T_j = 25\text{ (125) }^\circ\text{C}$		1,2 (1,3)	1,5 (1,6)	V				
r_{CE}	$T_j = 25\text{ (125) }^\circ\text{C}$		1,8 (2,3)	2,1 (2,7)	m Ω				
I_{CES}	$V_{GE} = 0\text{ V}$, $V_{CE} = V_{CES}$, $T_j = 25\text{ (125) }^\circ\text{C}$		(45)	1,2	mA				
$E_{on} + E_{off}$	$I_C = 750\text{ A}$, $V_{CC} = 600\text{ V}$ $T_j = 125\text{ }^\circ\text{C}$, $V_{CC} = 900\text{ V}$			225 397	mJ mJ				
$R_{CC'} + EE'$	terminal chip, $T_j = 125\text{ }^\circ\text{C}$		0,17		m Ω				
L_{CE}	top, bottom		5		nH				
C_{CHC}	per phase, AC-side		4,2		nF				
Inverse diode									
$V_F = V_{EC}$	$I_F = 750\text{ A}$, $T_j = 25\text{ (125) }^\circ\text{C}$		2,1 (2)	2,6	V				
V_{TO}	$T_j = 25\text{ (125) }^\circ\text{C}$		1,3 (1)	1,4 (1,1)	V				
r_T	$T_j = 25\text{ (125) }^\circ\text{C}$		1,1 (1,3)	1,5 (1,7)	m Ω				
E_{rr}	$I_C = 750\text{ A}$, $V_{CC} = 600\text{ V}$ $T_j = 125\text{ }^\circ\text{C}$, $V_{CC} = 900\text{ V}$			29 37	mJ mJ				
Mechanical data									
M_{dc}	DC terminals, SI Units	6		8	Nm				
M_{ac}	AC terminals, SI Units	13		15	Nm				
w	SKiIP® 2 System w/o heat sink		2,7		kg				
w	heat sink		6,6		kg				
Thermal characteristics (P16 heat sink; 295 m³/h); " r " reference to temperature sensor									
$R_{th(j-s)I}$	per IGBT			0,03	K/W				
$R_{th(j-s)D}$	per diode			0,083	K/W				
$R_{th(s-a)}$	per module			0,036	K/W				
Z_{th}	R_i (mK/W) (max. values)			$\tau_{i(s)}$					
	1	2	3	4	1	2	3	4	
$Z_{th(j-r)I}$		3	23	4	0	1	0,13	0,001	1
$Z_{th(j-r)D}$		9	64	10	0	1	0,13	0,001	1
$Z_{th(r-a)}$		11,1	18,3	3,5	3,1	204	60	6	0,02



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SKiiP 942GB120-3D



SKiiP[®] 2

Absolute Maximum Ratings		$T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified	
Symbol	Conditions	Values	Units
V_{S1}	stabilized 15 V power supply	18	V
V_{S2}	unstabilized 24 V power supply	30	V
V_{iH}	input signal voltage (high)	15 + 0,3	V
dv/dt	secondary to primary side	75	kV/ μ s
V_{isolIO}	input / output (AC, r.m.s., 2s)	3000	Vac
V_{isol12}	output 1 / output 2 (AC, r.m.s., 2s)	1500	Vac
f_{sw}	switching frequency	16	kHz
f_{out}	output frequency for $I=I_C$; sin.	1	kHz
T_{op} (T_{stg})	operating / storage temperature	- 40 ... + 85	$^\circ\text{C}$

2-pack - integrated intelligent Power System

2-pack integrated gate driver

SKiiP 942GB120-3D

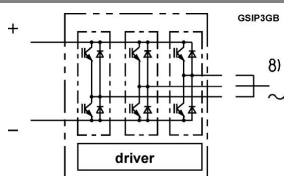
Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 60068-1 (climate) 25/85/56

Characteristics		$(T_a = 25\text{ }^\circ\text{C})$			
Symbol	Conditions	min.	typ.	max.	Units
V_{S1}	supply voltage stabilized	14,4	15	15,6	V
V_{S2}	supply voltage non stabilized	20	24	30	V
I_{S1}	$V_{S1} = 15\text{ V}$	$260+490*f/f_{max}+1,2*(I_{AC}/A)$			mA
I_{S2}	$V_{S2} = 24\text{ V}$	$200+360*f/f_{max}+0,85*(I_{AC}/A)$			mA
V_{iT+}	input threshold voltage (High)	12,3			V
V_{iT-}	input threshold voltage (Low)	4,6			V
R_{IN}	input resistance	10			k Ω
$t_{d(on)IO}$	input-output turn-on propagation time	1,5			μ s
$t_{d(off)IO}$	input-output turn-off propagation time	1,4			μ s
$t_{pERRRESET}$	error memory reset time	9			μ s
t_{TD}	top / bottom switch : interlock time	3,3			μ s
$I_{analogOUT}$	8 V corresponds to max. current of 15 V supply voltage (available when supplied with 24 V)	900			A
$I_{Vs1outmax}$	output current at pin 12/14	50			mA
I_{A0max}	output current at pin 12/14	5			mA
V_{O1}	logic low output voltage	0,6			V
V_{O1}	logic high output voltage	30			V
I_{TRIPSC}	over current trip level ($I_{analog OUT} = 10\text{ V}$)	1125			A
I_{TRIPLG}	ground fault protection	120			A
T_{tp}	over temperature protection	110			$^\circ\text{C}$
U_{DCTRIP}	trip level of U_{DC} -protection ($U_{analog OUT} = 9\text{ V}$); (option)	900			V

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Case S 3